

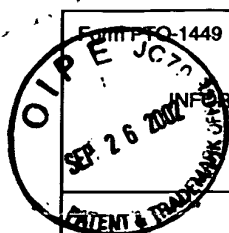
Form PTO-1449		US Dept. of Commerce PATENT & TRADEMARK OFFICE		ATTY DOCKET NO. D/A0577Q1		APPLICATION NO. 09/998,334	
INFORMATION DISCLOSURE STATEMENT (Use several sheets if necessary)				APPLICANT Linda Romano et al.			
				FILING DATE 12/3/01		GROUP ART UNIT 2811	
U.S. PATENT DOCUMENTS							
EXAMINER INITIAL	DOCUMENT NUMBER	PUBLICATION DATE	NAME OF PATENTEE		CLASS	SUB CLASS	

FOREIGN PATENT DOCUMENTS

	COUNTRY	DOCUMENT NUMBER	PUBLICATION DATE	NAME OF PATENTEE OR APPLICANT	TRANSLATION Y/N

OTHER DOCUMENTS (Including Author (in CAPS), Title, Publication Date, Pages, etc.)

J. Y.	KAZAWA, T. et al., "Fabrication of GaN Field Emitter Arrays by Selective Area Growth Technique", J. Vac. Sol. Technol. B 16(2), Mar./Apr. 1998, 833-834
J. Y.	YOUTSEY, C. et al., "Gallium Nitride Whiskers Formed by Selective Photoenhanced Wet Etching of Dislocations", Applied Physics Letters, Volume 73, Number 6, 10 August 1998, 797-799
EXAMINER <i>[Signature]</i> DATE CONSIDERED 4/28/03	
Examiner: Initial if citation considered, whether or not citation is in conformance with M.P.E.P. 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.	



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INFORMATION DISCLOSURE STATEMENT (Use several sheets if necessary)		APPLICANT Romano et al.	
		FILING DATE 12-3-01	GROUP ART UNIT 2879

U.S. PATENT DOCUMENTS					
EXAMINER INITIAL	DOCUMENT NUMBER	PUBLICATION DATE	NAME OF PATENTEE	CLASS	SUB CLASS
JWM <i>A.S.</i>	3,805,601	4/23/74	Jeffers	73	88.5
CKW <i>A.S.</i>	3,922,475	11/25/75	Manasevit	428	539
JJ <i>A.S.</i>	5,394,006	2/28/95	Lin	257	506
DM <i>A.S.</i>	5,684,319	11/4/97	Hebert	257	336
SLO <i>A.S.</i>	5,825,122	10/20/98	Givargizov	313	336
CB <i>A.S.</i>	6,165,808	12/26/00	Zhang	438	20

FOREIGN PATENT DOCUMENTS					
	COUNTRY	DOCUMENT NUMBER	PUBLICATION DATE	NAME OF PATENTEE OR APPLICANT	TRANSLATION Y/N

OTHER DOCUMENTS (Including Author (in CAPS), Title, Publication Date, Pages, etc.)	
<i>A.S.</i>	C. YOUTSEY, L.T. ROMANO, I. ADESIDA, "Gallium Nitride Whiskers Formed by Selective Photoenhanced Wet Etching of Dislocations," <u>Applied Physics Letters</u> , Vol. 73, No. 6, 10 August 1998, pp.797-799
<i>A.S.</i>	T. KOZAWA, M. SUZUKI, V. TAGA, Y. GOTOH, J. ISHIKAWA, "Fabrication of GaN Field Emitter Arrays by Selective Area Growth Technique," J. Vac. Sci. Technol. B 16(2), Mar/Apr. 1998, pp.833-835
EXAMINER <i>[Signature]</i>	DATE CONSIDERED 4/28/03
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